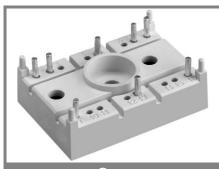
SK 120 KQ



SEMITOP® 2

Antiparallel Thyristor Module

SK 120 KQ

Preliminary Data

Features

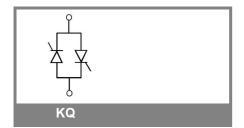
- Compact Design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passived thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications

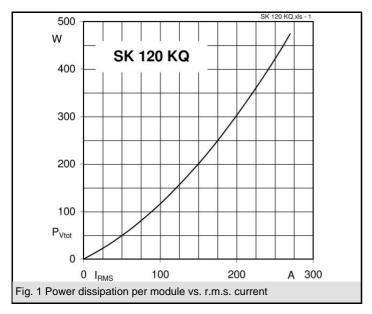
- Soft starters
- Light control (studios, theaters...)
- Temperature control

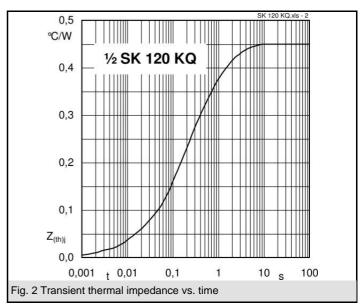
V _{RSM}	V_{RRM}, V_{DRM}	I _{RMS} = 134 A (full conduction)
V	V	(T _s = 85 °C)
900	800	SK 100 KQ 08
1300	1200	SK 100 KQ 12
1700	1600	SK 100 KQ 16

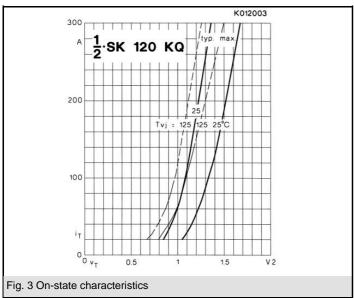
Symbol	Conditions	Values	Units
I _{RMS}	W1C ; sin. 180° ; T _s = 100°C	94	Α
	W1C ; sin. 180° ; T _s = 85°C	134	Α
I _{TSM}	T _{vi} = 25 °C ; 10 ms	2000	Α
	T _{vi} = 125 °C ; 10 ms	1800	Α
i²t	T _{vj} = 25 °C ; 8,310 ms	20000	A²s
	T _{vj} = 125 °C ; 8,310 ms	16200	A²s
V _T	T _{vi} = 25 °C, I _T = 300 A	max. 1,85	V
$V_{T(TO)}$	T _{vi} = 125 °C	max. 0,9	V
r _T	T _{vi} = 125 °C	max. 3,5	mΩ
$I_{DD};I_{RD}$	$T_{vj} = 25 ^{\circ}\text{C}, V_{RD} = V_{RRM}$	max. 1	mA
	T_{vj} = 125 °C, $V_{RD} = V_{RRM}$	max. 20	mA
t _{gd}	$T_{vj} = 25 ^{\circ}\text{C}, I_{G} = 1 \text{A}; di_{G}/dt = 1 \text{A/}\mu\text{s}$	1	μs
t _{gr}	$V_{D} = 0.67 * V_{DRM}$	2	μs
(dv/dt) _{cr}	T _{vi} = 125 °C	1000	V/µs
(di/dt) _{cr}	T _{vi} = 125 °C; f= 5060 Hz	100	A/µs
t _q	T _{vi} = 125 °C; typ.	80	μs
I _H	T_{vi}^{-3} = 25 °C; typ. / max.	100 / 200	mA
IL	$T_{vj}^{'}$ = 25 °C; R _G = 33 Ω; typ. / max.	200 / 500	mA
V _{GT}	$T_{vi} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 2	V
I _{GT}	$T_{vi}^{s} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 100	mA
V_{GD}	T _{vi} = 125 °C; d.c.	max. 0,25	V
I_{GD}	T _{vj} = 125 °C; d.c.	max. 5	mA
$R_{th(j-s)}$	cont. per thyristor	0,45	K/W
	sin 180° per thyristor	0,47	K/W
$R_{th(j-s)}$	cont. per W1C	0,225	K/W
0 /	sin 180° per W1C	0,235	K/W
T_{vi}		-40 + 125	°C
T _{stg}		-40 + 125	°C
T _{solder}	terminals, 10s	260	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 / 2500	V~
M_s	Mounting torque to heatsink	2,0	Nm
M_t			Nm
а			m/s²
m		19	g
Case	SEMITOP® 2	T 2	

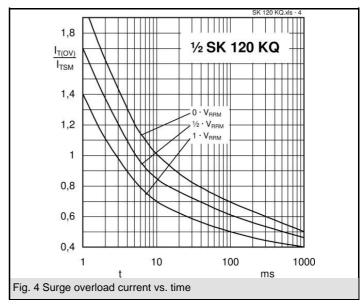


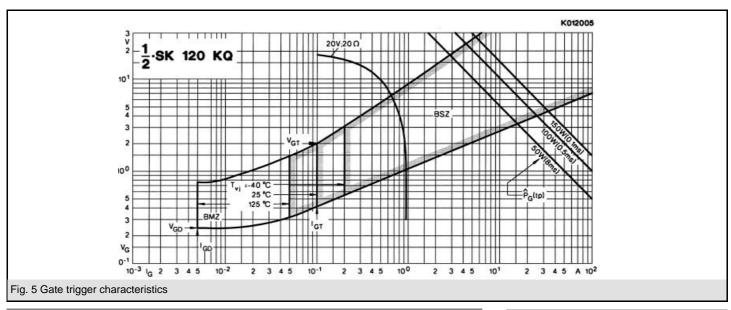
SK 120 KQ

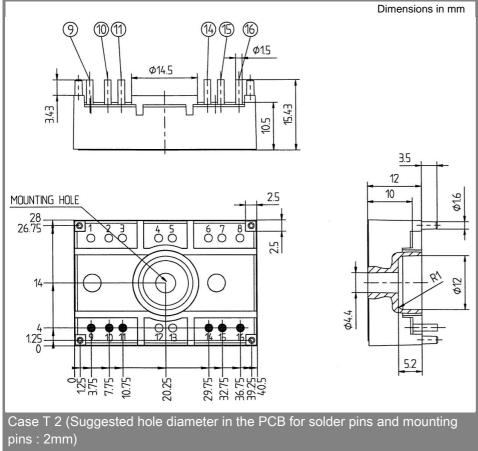


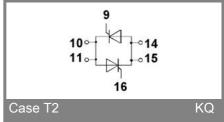












This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.